
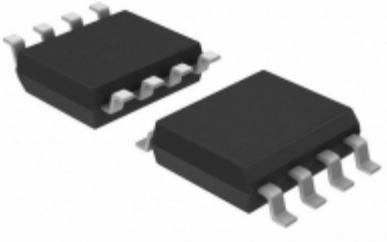


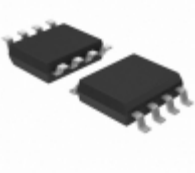



	<h2>SI4330DY-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI4330DY-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2N-CH 30V 6.6A 8-SOIC</p> <p>Datenblätter:  SI4330DY-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 36043 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI4330DY-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2N-CH 30V 6.6A 8-SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	36043 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.1W
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6.6A
Rds On (Max) @ Id, Vgs	16.5 mOhm @ 8.7A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)

SI4330DY-T1-E3 ist neu im Original, Suche SI4330DY-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4330DY-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI4330DY-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI4330BDY-T1-GE3 V SI4330BDY-T1-GE3 V</p>	 <p>SI4336DY VIS SI4336DY VIS</p>	 <p>SI4330DY-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 30V 6.6A 8-SOIC</p>	 <p>SI4330DY VISHAY SI4330DY VISHAY</p>
 <p>SI4334DY-T1-E3 VISHAY SI4334DY-T1-E3 VISHAY</p>	 <p>SI4330DY-T1 VISHAY SI4330DY-T1 VISHAY</p>	 <p>SI4330DY-T1-E3. VISHAY SI4330DY-T1-E3. VISHAY</p>	 <p>SI4330DY-T1-GE3 Electro-Films (EF1) / Vishay MOSFET 2N-CH 30V 6.6A 8-SOIC</p>

heiße Teile

Mehr

⊗ SI4286DY-T1-GE3	↔ Si4288DY	↔ SI4288DY-T1-GE3	D SI4288DY-T1-GE3	↔ SI4300-BM
⊣ SI4300-E-BM	⊗ SI4300DY-T1-E3	D SI4308DY-T1	↔ SI4308DY-T1-E3	↔ SI4311-B21-GMR
⊗ SI4320-J1-FTR	⊣ SI4320DY	⊗ SI4320DY-T1-E3	↔ SI4320DY-T1-E3	↔ SI4322-A0-FT
D SI4322-A0-FTR	⊗ SI4322DY-T1-E3	⊣ SI4322DY-T1-E3	⊗ SI4324DY	↔ SI4324DY-T1-E3
↔ SI4324DY-T1-E3	↔ SI4326DY-T1-E3	⊗ SI4330BDY-T1-GE3	⊣ SI4330DY-T1	↔ SI4330DY-T1-E3
↔ SI4330DY-T1-E3.	↔ SI4334DY-T1-E3	D SI4336DY	⊗ SI4336DY-E3	⊣ SI4336DY-T1-E3
⊗ SI4336DY-T1-E3	D SI4340CDY-T1-E3	↔ SI4340CDY-T1-E3	↔ SI4340CDY-T1-E3-S	↔ SI4340DY
⊣ SI4340DY-T1	⊗ SI4340DY-T1-E3	↔ SI4340DY-T1-E3	↔ SI4346DY	↔ SI4346DY-T1-E3
⊗ SI4346DY-T1-E3	⊣ SI4346DY-T1-GE3	⊗ SI4346DY-T1-GE3	D SI4348DY	↔ SI4348DY-T1-E3
↔ SI4348DY-T1-E3	⊗ SI4348DY-T1-GE3	⊣ SI4354DY-T1-E3	⊗ SI4354DY-T1-E3	↔ SI4355-B1A-FMR

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